Switch-mode Power Rectifier 150 V, 20 A

MBRF20H150CTG, MBR20H150CTG

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capability
- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics:

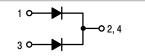
- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO-220 & TO-220FP)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

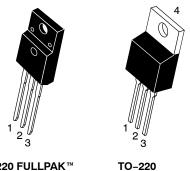


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SCHOTTKY BARRIER RECTIFIER 20 AMPERES, 150 VOLTS

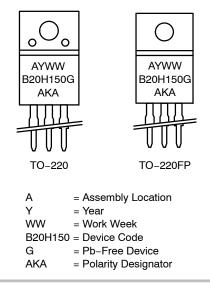




TO-220 FULLPAK™ CASE 221D

TO-220 CASE 221A STYLE 6

MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information on page 1 of this data sheet.

MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	150	V
Average Rectified Forward Current (Rated V_R) T _C = 134°C	(Per Leg) (Per Device)	I _{F(AV)}	10 20	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, s	I _{FSM}	180	A	
Operating Junction Temperature (Note 1)		ТJ	-20 to +150	°C
Storage Temperature		T _{stg}	-65 to +150	°C
Voltage Rate of Change (Rated V_R)		dv/dt	10,000	V/μs
ESD Ratings:	Machine Model = C Human Body Model = 3B		> 400 > 8000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

Rating		Symbol	Value	Unit
Maximum Thermal Resistance (MBR20H150CTG)	– Junction-to-Case – Junction-to-Ambient	R _θ JC	2.0 45	°C/W
(MBRF20H150CTG)	– Junction-to-Case	$R_{ heta JA} \ R_{ heta JC}$	2.5	

ELECTRICAL CHARACTERISTICS (Per Diode Leg)

Rating	Symbol	Тур	Max	Unit
$\label{eq:linear} \begin{array}{l} \mbox{Maximum Instantaneous Forward Voltage (Note 2)} \\ (I_F = 5 \mbox{ A}, \mbox{ T}_C = 25^\circ C) \\ (I_F = 5 \mbox{ A}, \mbox{ T}_C = 125^\circ C) \\ (I_F = 10 \mbox{ A}, \mbox{ T}_C = 25^\circ C) \\ (I_F = 10 \mbox{ A}, \mbox{ T}_C = 125^\circ C) \end{array}$	V _F	0.72 0.57 0.87 0.65	0.60 0.68	V
$\begin{array}{l} \mbox{Maximum Instantaneous Reverse Current (Note 2)} \\ (Rated DC Voltage, T_C = 25^{\circ}C) \\ (Rated DC Voltage, T_C = 125^{\circ}C) \end{array}$	İR		50 30	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width = $300 \ \mu$ s, Duty Cycle $\leq 2.0\%$.

ORDERING INFORMATION

Device Order Number	Package Type	Shipping
MBRF20H150CTG	TO-220FP (Pb-Free)	50 Units / Rail
MBR20H150CTG	TO-220 (Pb-Free)	50 Units / Rail

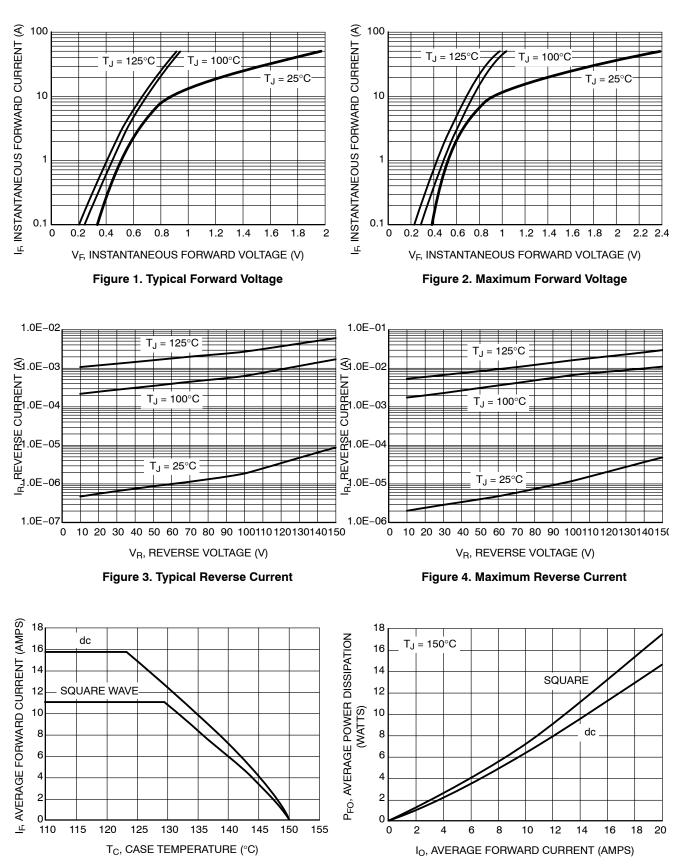
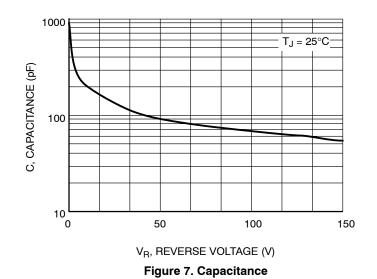
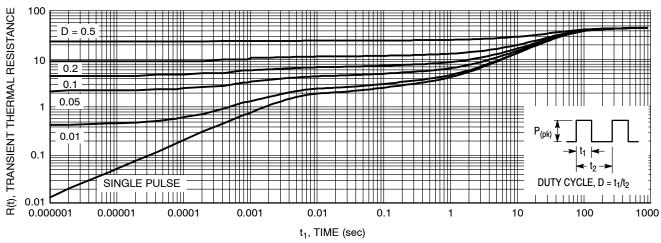


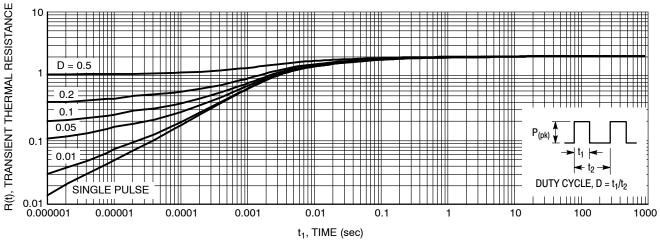
Figure 5. Current Derating

Figure 6. Forward Power Dissipation











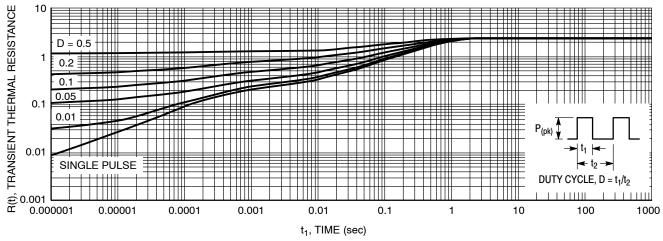


Figure 10. Thermal Response Junction-to-Case for MBRF20H150CTG

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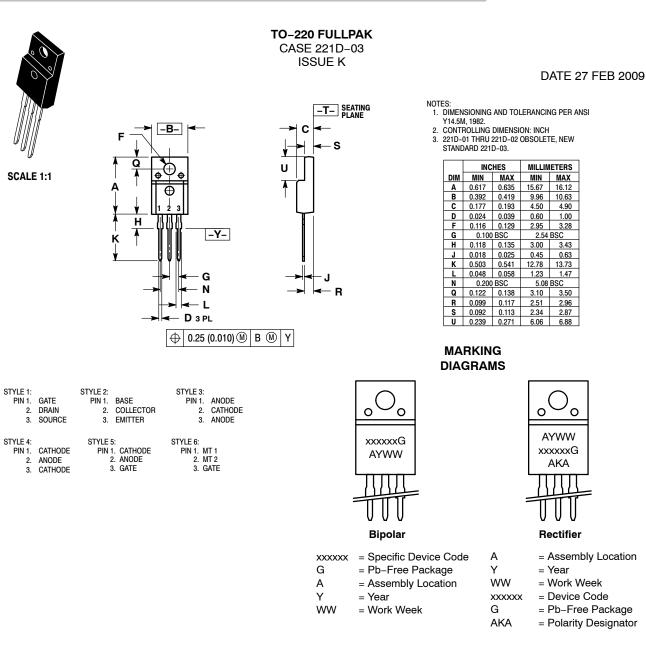
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			Г		INC	HES	MILLIM	ETERS	
				ым 🛛	MIN.	MAX.	MIN.	MAX.	
	2 3			A	0.570	0.620	14.48	15.75	
				в	0.380	0.415	9.66	10.53	
н —	₩₩			с	0.160	0.190	4.07	4.83	
	7 \7	H I		D	0.025	0.038	0.64	0.96	
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				н	0.110	0.161	2.80	4.10	
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	N 🖛			R	0.080	0.110	2.04	2.79	
				s	0.045	0.055	1.15	1.41	
				т	0.235	0.255	5.97	6.47	
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